INTRODUCTION

The S5T3170 is a complete Dual Tone Multiple Frequency (DTMF) receiver that is fabricated by low power CMOS and the Switched-Capacitor Filter technology. This LSI consists of band split filters, which separates counting section which verifies the frequency and duration of the received tones before passing the corresponding code to the output bus. It decodes all 16 DTMF tone pairs into a 4bits digital code. The externally required components are minimized by on chip provision of a differential input AMP, clock oscillator and latched three state interface. The on chip clock generator requires only a low cost TV crystal as an external component.


18–DIP–300A
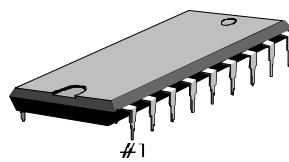
20–SOP–375
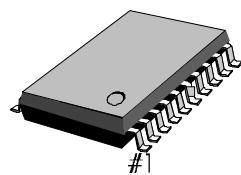
FEATURES

- Detects all 16 standard tones.

- Low power consumption: 15mW (Typ)

- Single power supply: 5V

- Uses inexpensive 3.58MHz crystal

- Three state outputs for microprocessor interface

- Good quality and performance for using in exchange system

- Power down mode/input inhibit

ORDERING INFORMATION

Device	Package	Operating
S5T3170X01-D0B0	18–DIP–300A	$-25°C — +75C$
S5T3170X01-S0B0	20–SOP–375	

APPLICATIONS

- PABX
- Central Office
- Paging Systems
- Remote Control
- Credit Card Systems
- Key Phone System
- Answering Phone
- Home Automation System
- Mobile Radio
- Remote Data Entry

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PIN CONFIGURATION

(18-DIP)

(20-SOP)
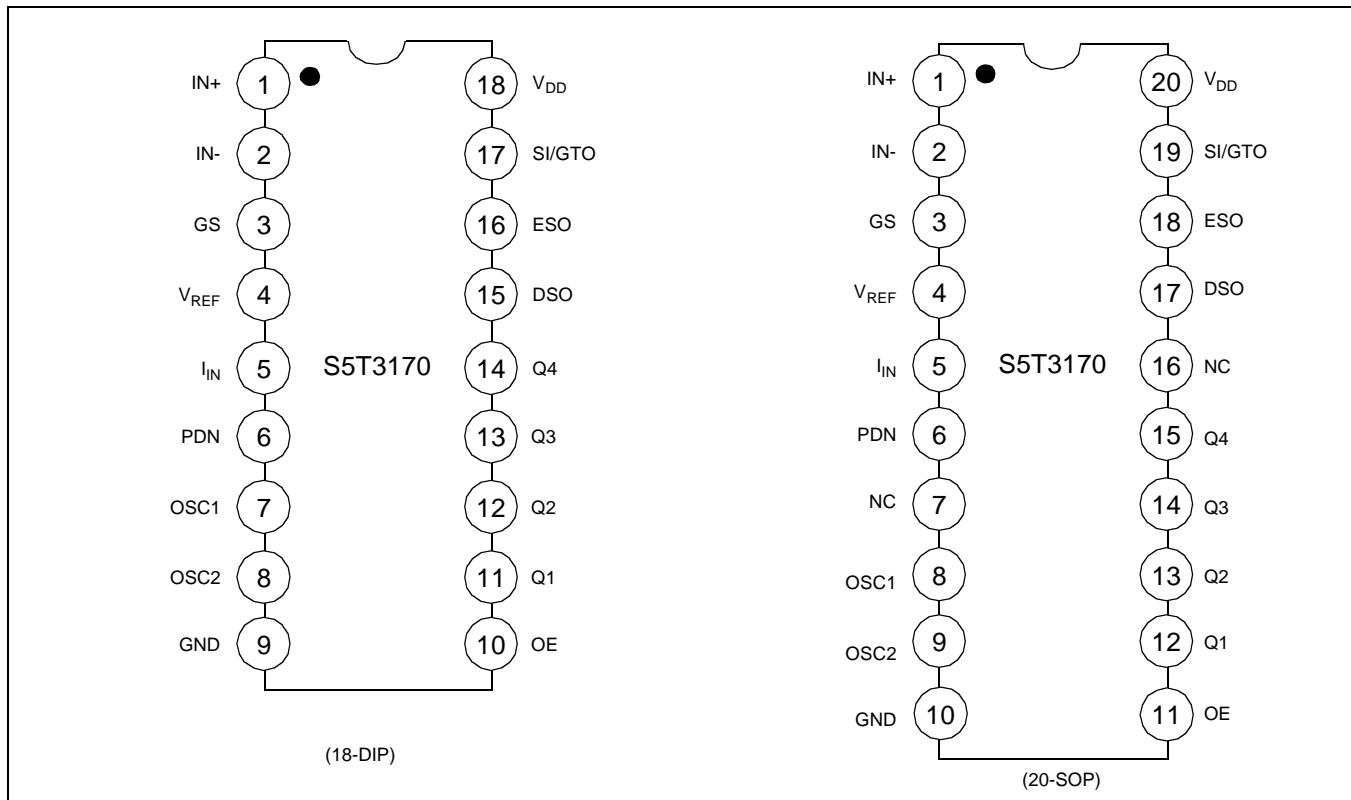
PIN DESCRIPTION

Pin No	Symbol	Description
1	IN +	Non inverting input of the internal amp.
2	IN −	Inverting input of the internal amp.
3	GS	Gain Select. The output used for gain adjustment of analog input signal with a feedback resistor.
4	V_{REF}	Reference Voltage output ($V_{DD}/2$, Typ) can be used to bias the internal amp input of $V_{DD}/2$.
5	I_{IN}	Input inhibit. High input states inhibits the detection of tones. This pin is pulled down internally.
6	PDN	Control input for the stand-by power down mode. Power down occurs when the signal on this input is in high states. This pin is pulled down internally.

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PIN DESCRIPTION (Continued)

Pin No	Symbol	Description
7, 8	OSC1 OSC2	Clock input/output. A inexpensive 3.579545MHz crystal connected between these pins completes internal oscillator. Also, external clock can be used.
9	GND	Ground pin.
10	OE	Output Enable input. Outputs Q1-Q4 are CMOS push-pull when OE is High and open circuited (High impedance) when disabled by pulling OE low. Internal pull up resistor built in.
11 - 14	Q1 - Q4	Three state data output. When enabled by OE, these digital outputs provide the hexadecimal code corresponding to the last valid tone pair received.
15	DSO	Delayed Steering Output. Indicates that valid frequencies have been present for the required guard time, thus constituting a valid signal. Presents a logic high when a received tone pair has been registered and the output latch is updated. Returns to logic low when the voltage on SI/GTO falls below V_{TH}.
16	ESO	Early Steering Outputs. Indicates detection of valid tone output a logic high immediately when the digital algorithm detects a recognizable tone pair. Any momentary loss of signal condition will cause ESO to return to low.
17	SI/GTO	Steering Input/Guard Time Output. A voltage greater the V_{TS} detected at SI causes the device to register the detected tone pair and update the output latch. A voltage less than V_{TS} frees the device to accept a new tone pair. The GTO output acts to reset the external steering time constant, and its state is a function of ESO and the voltage on SI
18	V_{DD}	Power Supply (+5V, Typ)

ABSOLUTE MAXIMUM RATINGS

Characteristics	Symbol	Value	Unit
Power Supply Voltage	V_{DD}	6	V
Analog Input Voltage Range	$V_{I (A)}$	$-0.3 - V_{DD} + 0.3$	V
Digital Input Voltage Range	$V_{I (D)}$	$-0.3 - V_{DD} + 0.3$	V
Output Voltage Range	V_O	$-0.3 - V_{DD} + 0.3$	V
Current On Any Pin	I_I	10	V
Operating Temperature	T_{OPR}	$-40 - +85$	mA
Storage Temperature	T_{STG}	$-60 - +150$	°C

ELECTRICAL CHARACTERISTICS

(V_{DD} = 5V, Ta = 25°C, unless otherwise noted)

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Operating Voltage	V_{DD}	–	4.75	–	5.25	V
Operating Current	I_{DD}	–	–	3.0	9.0	mA
Power Dissipation	P_D	–	–	15	45	mW
Input Voltage Low	V_{IL}	–	–	–	1.5	V
Input Voltage High	V_{IH}	–	3.5	–	–	V
Input Leakage Current	$I_{I(LKG)}$	V_{IN} = GND or V_{DD}	–	0.1	–	m
Pull Up Current On OE Pin	I_{PU}	OE = GND	–	7.5	15	μA
Analog Input Impedance	R_I	f_{IN} = 1KHz	8	10	–	MΩ
Steering Input Threshold Voltage	V_{TH}	–	2.2	–	2.5	V
Output Voltage Low	V_{OL}	No Load	–	–	0.03	V
	V_{OH}	No Load	4.97	–	–	V
Output Current (Sinking)	$I_{O(SINK)}$	V_{OL} = 0.4V	1	2.5	–	mA
Output Current (Sourcing)	$I_{O(SOURCE)}$	V_{OH} = 4.6V	0.4	0.8	–	mA
V_{REF} Output Voltage	$V_{O(REF)}$	–	2.4	–	2.8	V
V_{REF} Output Resistance	$R_{O(REF)}$	–	–	10	–	KΩ
Analog Input Offset Voltage	V_{IO}	–	–	25	–	mV
Power Supply Rejection Ratio	PSRR	Gain Setting Amp at 1KHz	–	60	–	dB
Common Mode Rejection Ratio	CMRR	– 3.0V < V_{IN} < 3.0V	–	60	–	dB
Open Loop Voltage Gain	G_V	Gain Setting Amp at 1KHz	–	65	–	dB
Open Loop Unit Gain Bandwidth	BW	–	–	1.5	–	MHz
Analog Output Voltage Swing	$V_{O(P-P)}$	R_L = 100K	–	4.5	–	V_{P-P}
Acceptable Capacitive Load	C_L	GS	–	100	–	pF
Acceptable Resistive Load	R_L	GS	–	50	–	KΩ
Analog Input Common Mode Voltage Range	V_{CM}	No Load	–	3.0	–	V_{P-P}
Valid Input Signal Range (each tone of composite signal)	$V_{I(VAL)}$	–	−29	–	1.0	dBm
Dual Tone Twist Accept	TW	–	–	±10	–	dB
Acceptable Frequency Deviation	Δf	–	–	–	±1.5% ± 2Hz	–
Frequency Deviation Reject	$Δf_R$	–	±3.5%	–	–	–

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ELECTRICAL CHARACTERISTICS (Continued)

(V_{DD} = 5V, Ta = 25°C, unless otherwise noted)

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Third Tone Tolerance	T3rd	–	–25	–16	–	dB
Noise Tolerance	TN	–	–	–12	–	dB
Dial Tone Tolerance	DT	–	18	22	–	dB
Crystal Clock Frequency	f_{CK}	–	3.5759	3.5795	3.5831	MHz
Maximum Clock Input Rise Time	$t_{R(MAX)}$	External Clock	–	–	110	nS
Maximum Clock Input Fall Time	$t_{F(MAX)}$	External Clock	–	–	110	nS
Acceptable Clock Input Duty Cycle	D_{CK}	External Clock	40	50	60	%
Acceptable Capacitive Load	D_L	OSC2 PIN	–	–	30	pF
Tone Present Detect Time	$t_{DET(P)}$	–	5	11	14	mS
Tone Absent Detect Time	$t_{DET(A)}$	–	0.5	4	8.5	mS
Minimum Tone Duration Accept	$t_{TDA(MIN)}$	User Adjustable	–	–	40	mS
Minimum Tone Duration Reject	$t_{TDR(MAX)}$	User Adjustable	20	–	–	mS
Acceptable Interdigit Pause	$t_{IDP(A)}$	User Adjustable	–	–	40	mS
Rejectable Interdigit Pause	$t_{IDP(R)}$	User Adjustable	20	–	–	mS
Propagation Delay Time SI to Q	$t_{D(SI-Q)}$	OE = High	–	8	11	µS
Propagation Delay Time SI to DSO	$t_{D(SI-D)}$	OE = High	–	12	16	µS
Output Data Setup Q to DSO	t_{SU}	OE = High	–	3.4	–	µS
Propagation Delay Time OE to Q (Enable)	$t_{D(QE-Q)EN}$	RL = 10K, CL = 50pF	–	50	60	nS
Propagation Delay Time OE to Q (Disable)	$t_{D(QE-Q)DIS}$	RL = 10K, CL = 50pF	–	300	–	nS

NOTES:

1. Digit sequence consists of all 16 DTMF tones.
2. Tone duration = 40mS, Tone pause = 40mS.
3. Nominal DTMF frequencies are used.
4. Both tones in the composite signal have an equal amplitude.
5. Tone pair is deviated by ± 1.5% ± 2Hz.
6. Bandwidth limited (3KHz) Gaussian Noise.
7. The precise dial tone frequencies are (350Hz and 440Hz) ± 2%.
8. For an error rate of better than 1 in 10000.
9. Referenced to lowest level frequency component in DTMF signal.
10. Minimum signal acceptance level is measured with specified maximum frequency deviation.
11. This item also applies to a third tone injected onto the power supply.
12. Referenced to Fig. 1 Input DTMF tone level at -28dBm.

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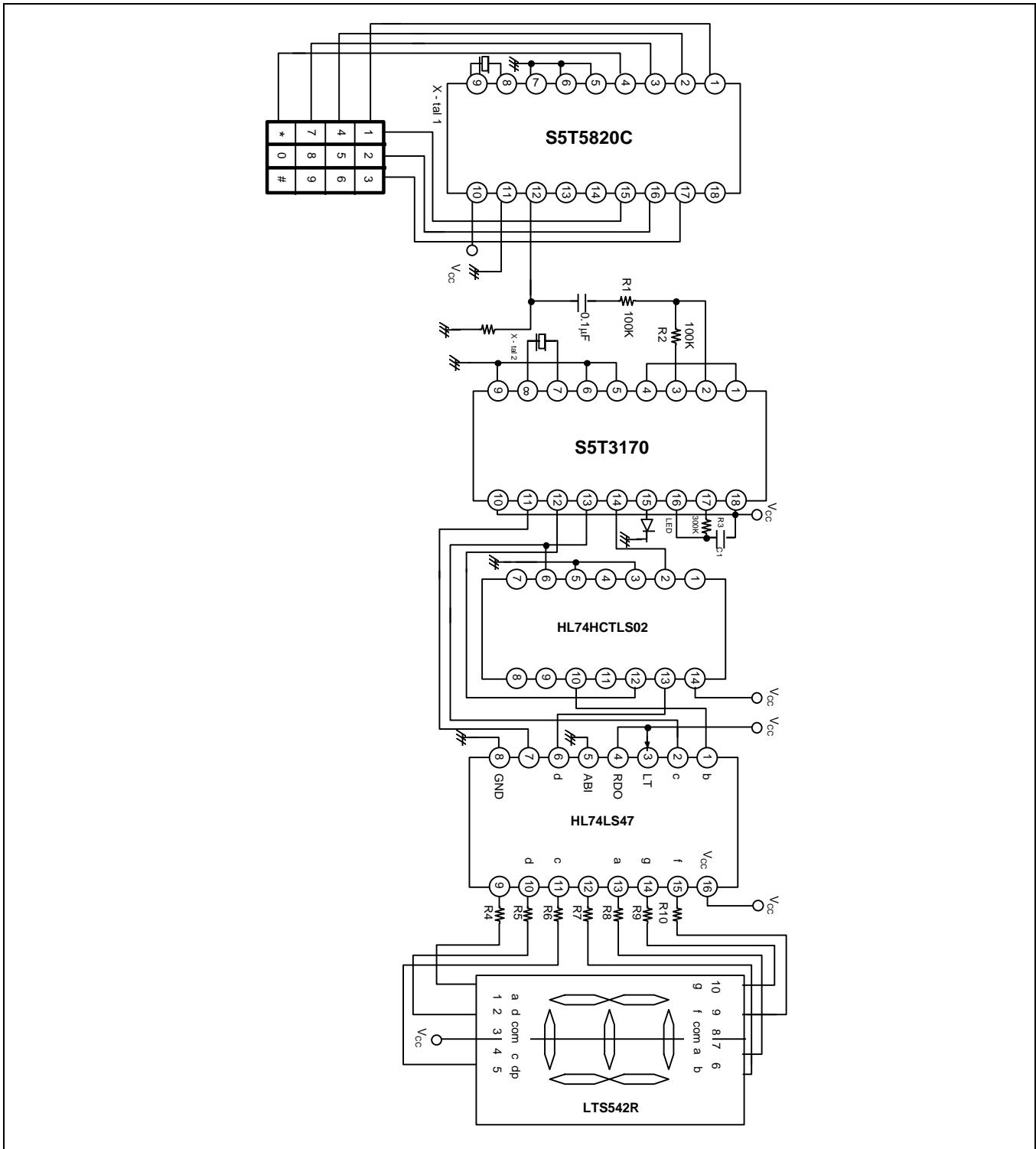
TEST CIRCUIT

**Figure 1. Test Circuit**

TIMING DIAGRAM
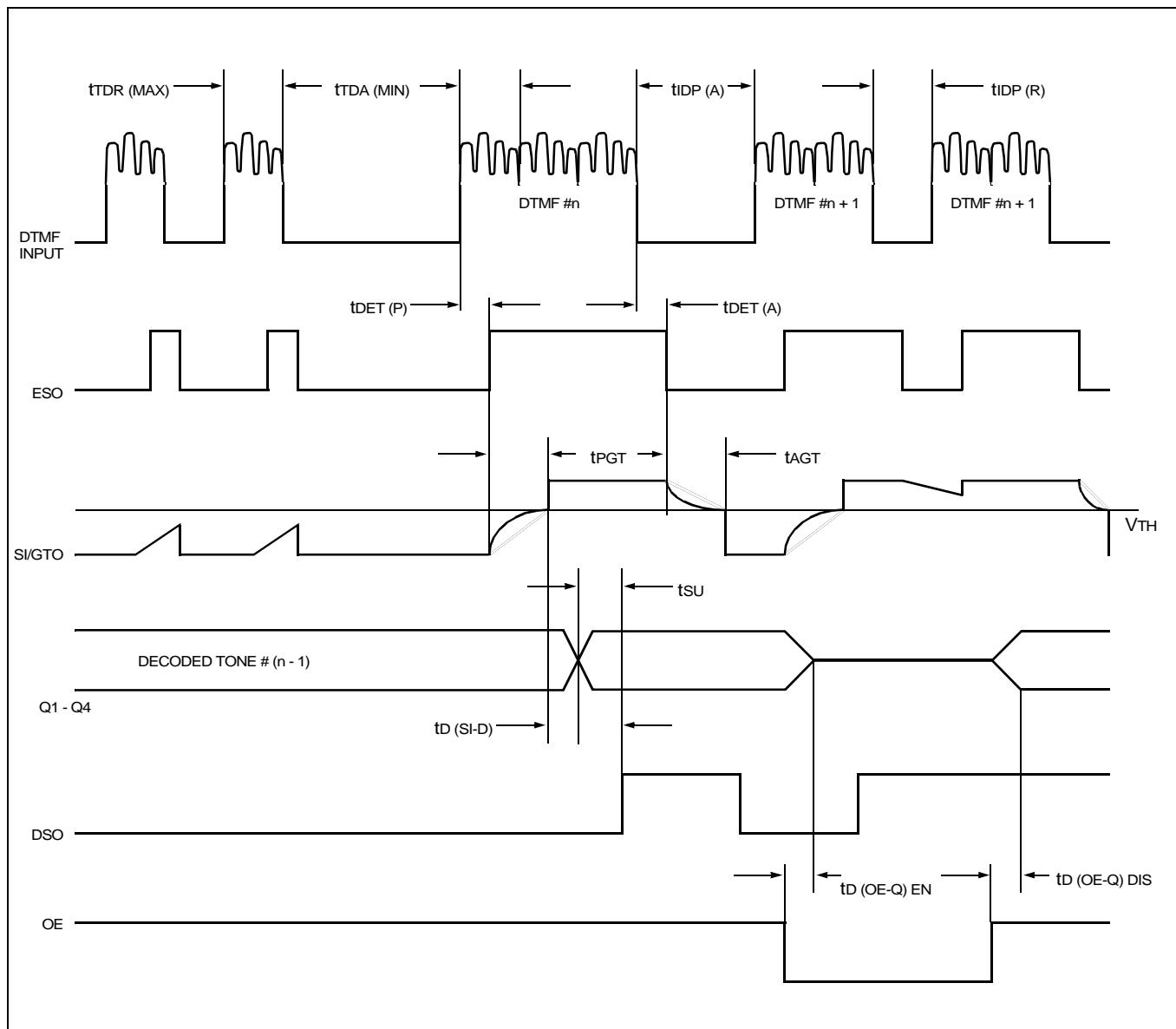
**Figure 2. Timing Diagram**

DIGITAL OUTPUT

Outputs Q1-Q4 are CMOS push pull when enabled (EO = High) and open circuited (high impedance) when disabled by pulling EO = Low. These digital outputs provide the hexadecimal code corresponding to the DTMF signals. The table below describes the hexadecimal.

NO	Low Frequency	High Frequency	OE	Q4	Q3	Q2	Q1
1	697	1209	H	0	0	0	1
2	697	1336	H	0	0	1	0
3	697	1477	H	0	0	1	1
4	770	1209	H	0	1	0	0
5	770	1336	H	0	1	0	1
6	770	1477	H	0	1	1	0
7	852	1209	H	0	1	1	1
8	852	1336	H	1	0	0	0
9	852	1477	H	1	0	0	1
0	941	1336	H	1	0	1	0
*	941	1209	H	1	0	1	1
#	941	1477	H	1	1	0	0
A	697	1633	H	1	1	0	1
B	770	1633	H	1	1	1	0
C	852	1633	H	1	1	1	1
D	941	1633	H	0	0	0	0
ANY	-	-	L	Z	Z	Z	Z

NOTE:

Z   : High Impedance

H   : High Logic Level

L   : Low Logic Level

APPLICATION CIRCUIT
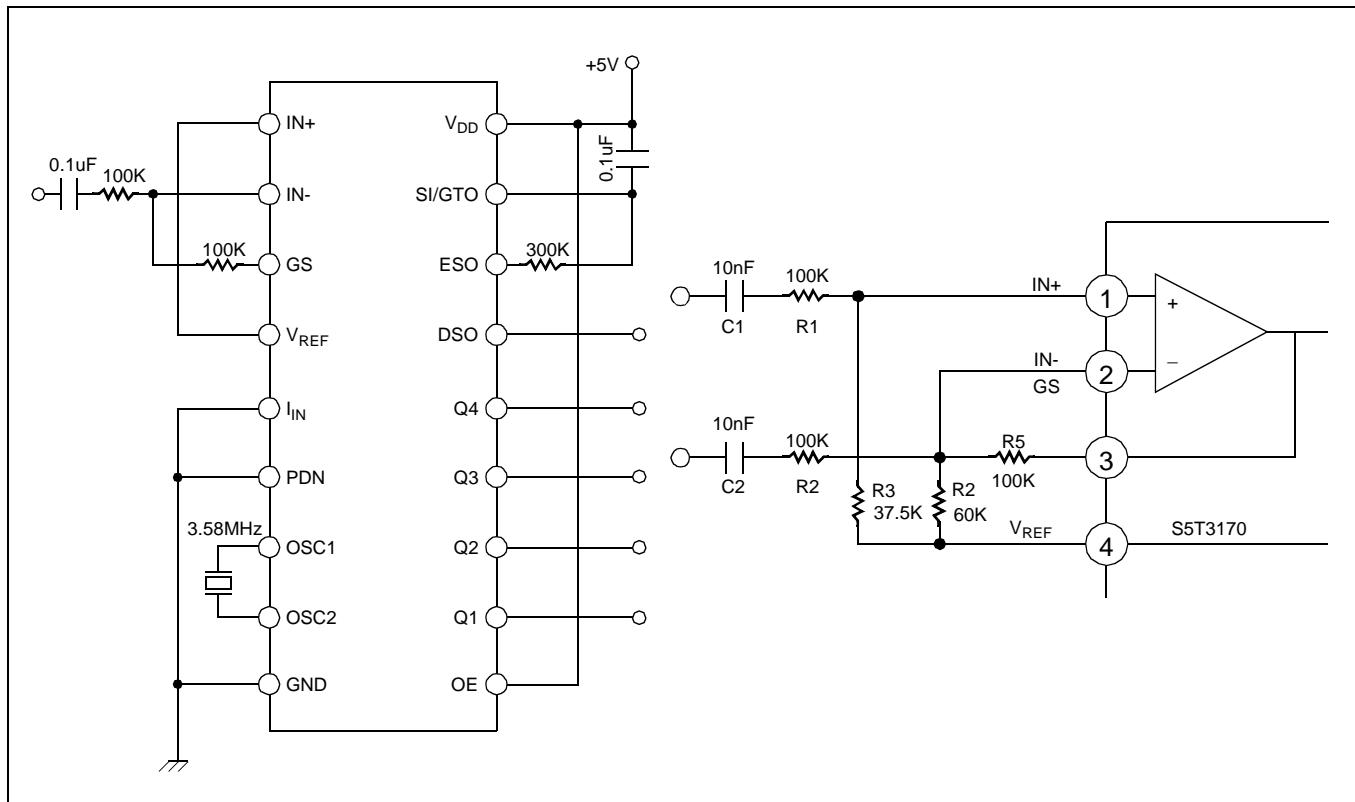
All resistors are 1% tolerance

All capacitors are 5% tolerance

Figure 3. Single Ended Input Configuration

R3 = R2R5/(R2+R5), VOLTAGE GAIN = R5/R1

INPUT IMPEDANCE $2\sqrt{R_1^2 + (1/wC)^2}$

All resistors are 1% tolerance

All resistors are 1% tolerance

All capacitors are 5% tolerance

Figure 4. Differential Ended Input Configuration
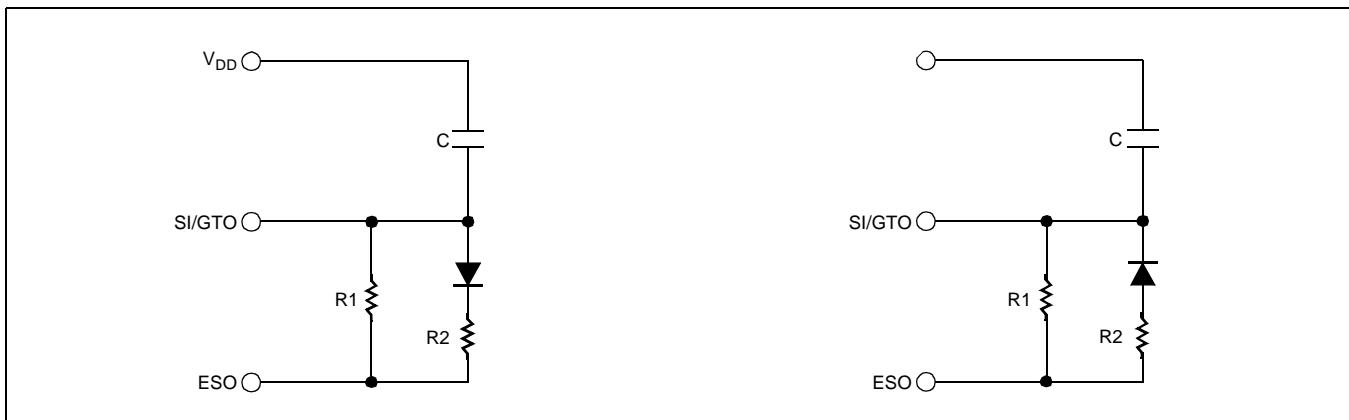
t_{PGT} = (R1C) In ($V_{DD}/V_{DD}-V_{TH}$)

t_{AGT} = (RPC) In (V_{DD}/V_{TST})

R_P = R1R2/(R1 + R2)

Decreasing t_{AGT} (t_{PGT} > t_{AGT})

t_{PGT} = (RPC) In ($V_{DD}/V_{DD}-V_{TH}$)

t_{AGT} = (R1C) In (V_{DD}/V_{TH})

R_P = R1R2 (R1 + R2)

Decreasing t_{PGT} (t_{PGT}< t_{AGT})

Figure 5. Guard Time Adjustment
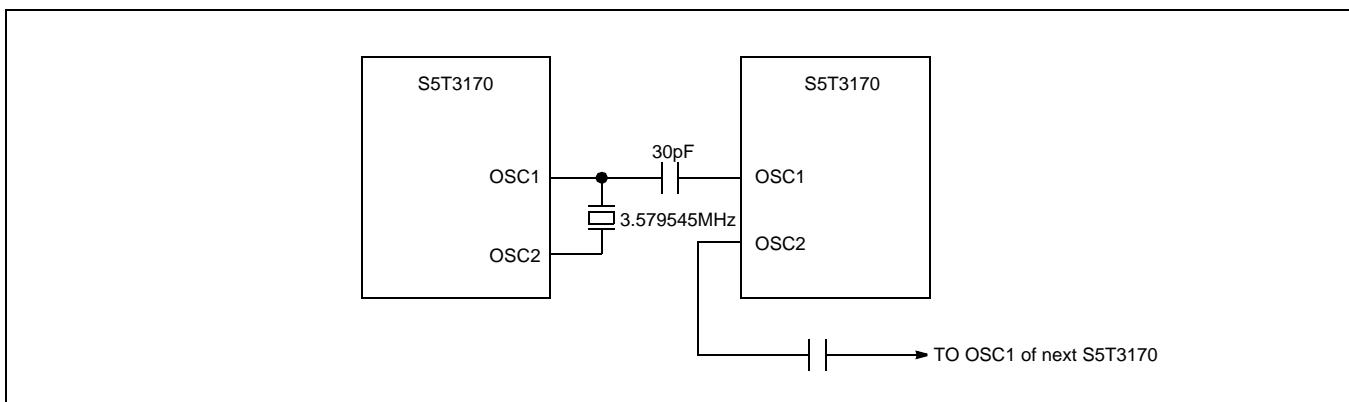
Figure 6. Oscillator Connection